



IFW
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

RALF VAN BENTUM
MANFRED HORSTMANN

Serial No.: 10/624,712

Filed: July 22, 2003

For: TECHNIQUE FOR FORMING
CONTACTS FOR BURIED DOPED
REGIONS IN A SEMICONDUCTOR
DEVICE

Examiner: Lan Vinh

Group Art Unit: 1765

Att'y Docket: 2000.106700/DE0122

Customer No.: 23720

RESPONSE TO OFFICE ACTION DATED MAY 26, 2005

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

CERTIFICATE OF MAILING
37 C.F.R. 1.8

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date below:

June 21, 2005

Date

Mary Paul
Signature

This paper is submitted in response to the Office Action dated May 26, 2005, for which the three-month date for response is August 26, 2005.

A fee in the amount of \$550.00 is believed to be due in connection with the present paper. **The Director is authorized to deduct such fee, and any other fees required under 37 C.F.R. §§ 1.16 to 1.21, from the Advanced Micro Devices, Inc. Deposit Account No. 01-0365/DE0122.¹**

Reconsideration of the application in view of the following amendments and remarks is respectfully requested.

06/24/2005 RMEBRAHT 00000030 010365 10624712
01 FC:1202 550.00 DA

¹ In the event the monies in that account are insufficient, the Director is authorized to withdraw funds from Williams, Morgan & Amerson, P.C. Deposit Account No. 50-0786/2000.106700.